

Common Anode Silicon Dual Switching diodes

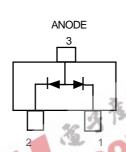
These Common Anode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

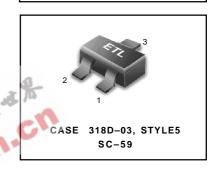
- \bullet Fast t $_{rr}$, < 10 ns
- Low C D, < 15 pF
- Available in 8 mm Tape and Reel
 Use M1MA151/2WAT1 to order the 7 inch/3000 unit reel.

 Use M1MA151/2WAT3 to order the 13 inch/10,000 unit reel.

M1MA151WAT1 M1MA152WAT1

SC-59 PACKAGE
COMMON ANODE
DUAL SWITCHING DIODES
40/80 V-100mA
SURFACE MOUNT





MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating		Symbol	Value	Unit
Reverse Voltage	M1MA151WAT1	V _R	40	Vdc
	M1MA152WAT1		80	
Peak Reverse Voltage	M1MA151WAT1	V _{RM}	40	Vdc
	M1MA152WAT1		80	
Forward Current	Single	I _F	100	mAdc
	Dual		150	
Peak Forward Current	Single	I _{FM}	225	mAdc
	Dual		340	
Peak Forward Surge Current	Single	I _{FSM} ⁽¹⁾	500	mAdc
	Dual		750	

THERMAL CHARACTERISTICS

Rating	Symbo	lMax	Unit
Power Dissipation	P _D	200	mW
Junction Temperature	Τ _J	150	°C
Storage Temperature	T stg	-55 to +1	50 °C

ELECTRICAL CHARACTERISTICS (T A = 25°C)

Characteristic		Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Currer	nt M1MA151WAT1	I _R	V _R = 35 V	_	0.1	μAdc
	M1MA152WAT1		$V_{R} = 75 V$	_	0.1	
Forward Voltage		V _F	I _F = 100 mA	-\	1.2	Vdc
Reverse Breakdown Voltage	M1MA151WAT1	V _R	I _R = 100 μA	40	_	Vdc
	M1MA152WAT1			80	_	
Diode Capacitance		Съ	$V_{R} = 0, f = 1.0 \text{ MHz}$	_	15	pF
Reverse Recovery Time		t _{rr} (2)	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V},$	_	10	ns
			$R_L = 100\Omega, I_m = 0.1 I_R$			

1. t = 1 SEC

2. t_{rr} Test Circuit

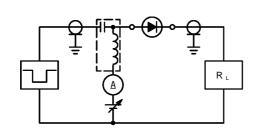


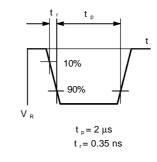
M1MA151WAT1 M1MA152WAT1

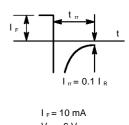
RECOVERY TIME EQUIVALENT TEST CIRCUIT

INPUT PULSE

OUTPUT PULSE

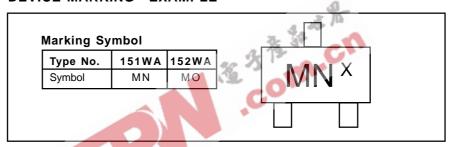






 $V_R = 6 V$ $R_L = 100 \Omega$

DEVICE MARKING—EXAMPLE



The "X" represents a smaller alpha digit Date Code. The Date Code indicates the actual month in which the part was manufactured.

SEMICONDUCTOR